

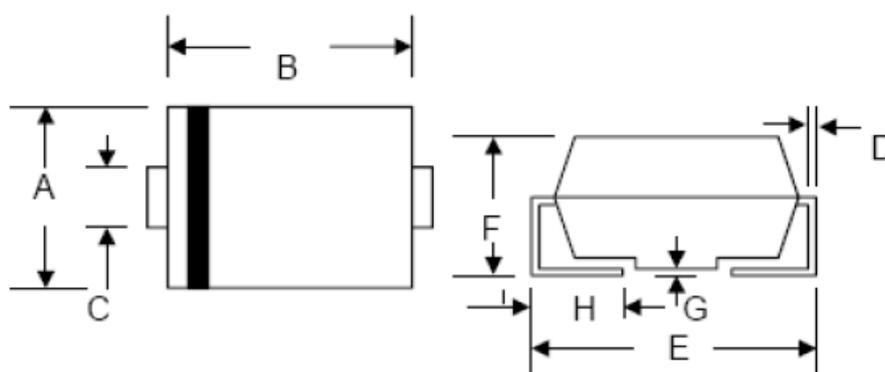
GS1A THRU GS1M
1.0A SURFACE MOUNT GLASS PASSIVATED RECTIFIER

Features:

- Glass Passivated Die Construction
- Ideally Suited for Automatic Assembly
- Low Forward Voltage Drop
- Low Power Loss
- Built-in Strain Relief
- Plastic Case Material has UL Flammability Classification Rating 94V-0
- This is a Pb – Free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Data:

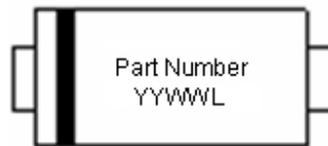
- Case: Molded plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode band or cathode Notch
- Weight: 0.064 grams (approx.)

Mechanical Dimensions: In mm / Inches


Dim.	SMA/DO-214AC			
	Min.	Max.	Min.	Max.
A	2.18	2.90	0.086	0.114
B	3.99	4.60	0.157	0.181
C	1.29	1.70	0.508	0.067
D	0.152	0.305	0.006	0.012
E	4.70	5.31	0.185	0.209
F	1.70	2.50	0.067	0.098
G	0.051	0.203	0.002	0.008
H	0.76	1.55	0.030	0.610
	In mm		In inch	

SMA

Marking Diagram:



First row: Part Number (GS1A, GS1B, GS1D, GS1G, GS1J, GS1K, GS1M)

Second row: YYWWL

YY is the manufacture year, WW is the manufacture week code, L is the wafer's Lot Number

Ordering Information

Device	Package	Shipping
GS1A GS1B GS1D GS1G GS1J GS1K GS1M	SMA (Pb-Free)	5000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings and Electrical characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	GS1A	GS1B	GS1D	GS1G	GS1J	GS1K	GS1M	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Average Rectified Output Current @ $T_L = 100^\circ\text{C}$	I_O	1.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	30							A
Forward Voltage @ $I_F = 1.0\text{ A}$	V_F	1.10							V
Peak Reverse Current @ $T_A = 25^\circ\text{C}$ At Rated DC Blocking Voltage @ $T_A = 125^\circ\text{C}$	I_{RM}	5.0 200							μA
Reverse Recovery Time(Note1)	t_{rr}	2.5							μS
Typical Junction Capacitance(Note2)	C_J	15							pF
Typical Thermal Resistance Junction to Lead (Note 3)	$R_{\theta JL}$	30							$^\circ\text{C/W}$
Operating Temperature Range	T_J	-65 to +175							$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-65 to +175							$^\circ\text{C}$

- Note: 1. Measured with $I_F = 0.5\text{A}$, $I_R = 1.0\text{A}$, $I_{rr} = 0.25\text{A}$.
 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
 3. Mounted on P.C. Board with 8.0mm² copper pad areas.



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